ABSOLUTE MAXIMUM RATINGS

PARAMETER		LIMIT	UNIT
Reference V+ to GND		-0.3 to +6	V
IN, COM, NC, NO [a]		-0.3 to (V+ + 0.3)	
Continuous current (any terminal)		± 20	mA
Peak current (pulsed at 1 ms, 10 % duty cycle)		± 40	
ESD (HBM) (MIL-STD-883, method 3015)		> 8000	V
ESD (CDM) (ANSI / ESDA / JEDEC® JS-002)		> 1000	
Latch up current, per JESD78		300	mA
Storage temperature (D suffix)		-65 to +125	°C
Power dissipation (packages) [b]	8-pin narrow body SOIC [c]	400	mW
	6-pin TSOP [d]	570	

Notes

a. Signals on SX, DX, or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate 6.5 mW/°C above 75 °C.
d. Derate 7 mW/°C above 70 °C.

SPECIFICATIONS (V+ = 3 V)

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 3 V, ± 10 %, V_{IN} = 0.8 V or 2.4 V [e]	TEMP. [a]	D SUFFIX -40 °C TO +85 °C			UNIT
				MIN. [c]	TYP. [b]	MAX. [c]	
Analog Switch							
Analog signal range [d]	V_{ANALOG}		Full	0	-	3	V
Drain-source on–resistance	$R_{DS(on)}$	V_{NO} or V_{NC} = 1.5 V, V+ = 2.7 V, I_{COM} = 5 mA	Room	-	35	50	Ω
			Full	-	-	65	
$R_{DS(on)}$ match [d]	$\Delta R_{DS(on)}$	V_{NO} or V_{NC} = 1.5 V	Room	-	0.4	2	
$R_{DS(on)}$ flatness [f]	$R_{DS(on)}$ flatness	V_{NO} or V_{NC} = 1 V and 2 V	Room	-	4	8	
NO or NC off leakage current [g]	$I_{NO/NC(off)}$	V_{NO} or V_{NC} = 1 V / 2 V, V_{COM} = 2 V / 1 V	Room	-100	5	100	pA
			Full	-5000	-	5000	
COM off leakage current [g]	$I_{COM(off)}$	V_{COM} = 1 V / 2 V, V_{NO} or V_{NC} = 2 V / 1 V	Room	-100	5	100	
			Full	-5000	-	5000	
Channel-on leakage current [g]	$I_{COM(on)}$	V_{COM} = V_{NO} or V_{NC} = 1 V / 2 V	Room	-200	5	200	
			Full	-10 000	-	10 000	
Digital Control							
Input current	I_{INL} or I_{INH}		Full	-	0.001	-	µA
Dynamic Characteristics							
Turn-on time	t_{ON}	V_{NO} or V_{NC} = 1.5 V	Room	-	43	120	ns
			Full	-	-	200	
Turn-Off Time	t_{OFF}		Room		16	50	
			Full	-	-	120	
Break-before-make time	t_d		Room	3	26	-	
Charge injection	Q_{INJ}	C_L = 1 nF, V_{gen} = 0 V, R_{gen} = 0 Ω	Room	-	-0.28	-	pC
Off-isolation	O_{IRR}	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz	Room	-	-80	-	dB
Crosstalk	X_{TALK}		Room	-	-108	-	
Source off capacitance	$C_{S(off)}$	f = 1 MHz	Room	-	4	-	pF
Channel-on capacitance	$C_{D(on)}$		Room	-	8	-	
Power Supply							
Power supply range	V+			2.7	-	5.5	V
Power supply current	I+	V+ = 3.3 V, V_{IN} = 0 V or 3.3 V		-	0.0003	1	µA

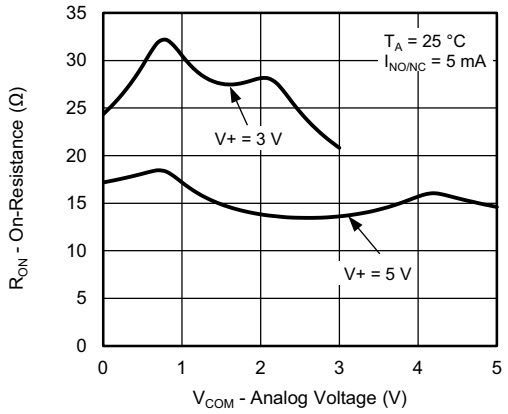
SPECIFICATIONS (V+ = 5 V)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS UNLESS OTHERWISE SPECIFIED** V+ = 5 V, ± 10 %, V_{IN} = 0.8 V or 2.4 V [e]	**TEMP.** [a]	**D SUFFIX** -40 °C to +85 °C			**UNIT**
				MIN. [c]	**TYP.** [b]	**MAX.** [c]	
Analog Switch							
Analog signal range [d]	V_{ANALOG}		Full	0	-	5	V
Drain-source on–resistance	$R_{DS(on)}$	V_{NO} or V_{NC} = 3.5 V, V+ = 4.5 V, I_{COM} = 5 mA	Room	-	17	25	Ω
			Full	-	-	35	
$R_{DS(on)}$ match [d]	$\Delta R_{DS(on)}$	V_{NO} or V_{NC} = 1.5 V	Room	-	0.4	2	
$R_{DS(on)}$ flatness [f]	$R_{DS(on)}$ flatness	V_{NO} or V_{NC} = 1 V, 2 V, and 3 V	Room	-	3.5	6	
NO or NC off leakage current	$I_{NO/NC(off)}$	V_{NO} or V_{NC} = 1 V / 4 V, V_{COM} = 4 V / 1 V	Room	-100	10	100	pA
			Full	-5000	-	5000	
COM off leakage current	$I_{COM(off)}$	V_{COM} = 1 V / 4 V, V_{NO} or V_{NC} = 4 V / 1 V	Room	-100	10	100	
			Full	-5000	-	5000	
Channel-on leakage current	$I_{COM(on)}$	V_{COM} = V_{NO} or V_{NC} = 1 V / 4 V	Room	-200	-	200	
			Full	-10 000	-	10 000	
Digital Control							
Input current	I_{INL} or I_{INH}		Full	-	0.001	-	µA
Dynamic Characteristics							
Turn-on time	t_{ON}	V_{NO} or V_{NC} = 3 V	Room	-	32	75	ns
			Full	-	-	150	
Turn-off time	t_{OFF}		Room	-	10	50	
			Full	-	-	100	
Break-before-make time	t_d		Room	3	22	-	
Charge injection	Q_{INJ}	C_L = 1 nF, V_{gen} = 0 V, R_{gen} = 0 Ω	Room	-	-0.78	-	pC
Off-isolation	O_{IRR}	R_L = 50 Ω, C_L = 5 pF, f = 1 MHz	Room	-	-80	-	dB
Crosstalk	X_{TALK}		Room	-	-108	-	
NC and NO capacitance	$C_{(off)}$	f = 1 MHz	Room	-	3.8	-	pF
Channel-on capacitance	$C_{D(on)}$		Room	-	7.8	-	
Power Supply							
Power supply range	V+			2.7	-	5.5	V
Power supply current	I+	V+ = 5.5 V, V_{IN} = 0 V or 5.5 V		-	0.0004	1	µA

Notes

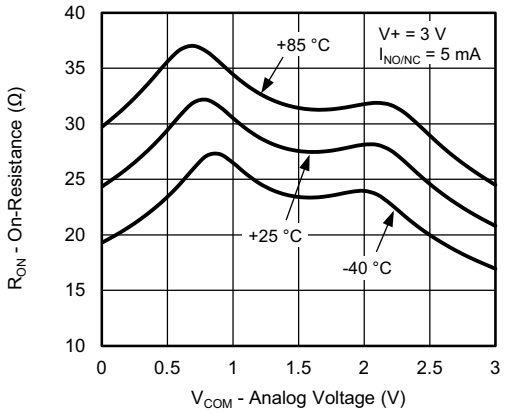
a. Room = 25 °C, Full = as determined by the operating suffix.
b. Typical values are for design aid only, not guaranteed nor subject to production testing.
c. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
d. Guarantee by design, nor subjected to production test.
e. V_{IN} = input voltage to perform proper function.
f. Difference of min and max values.
g. Guaranteed by 5 V leakage testing, not production tested.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

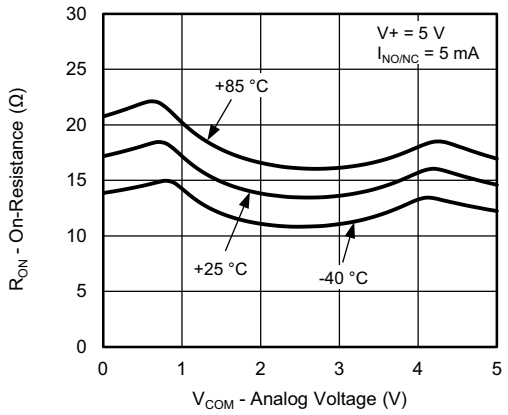
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



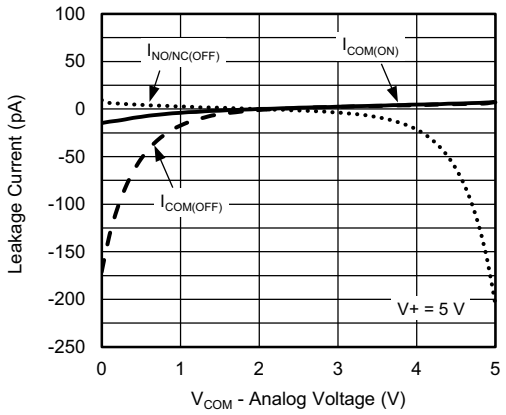
On-Resistance vs. Analog Voltage



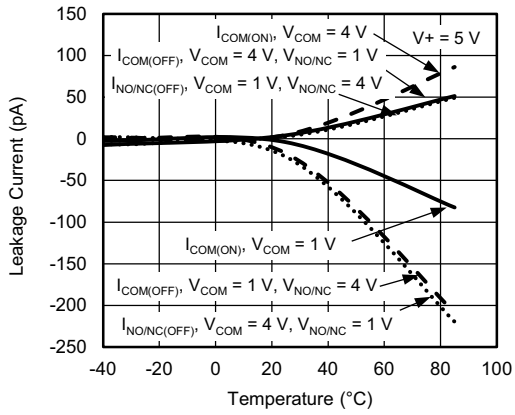
On-Resistance vs. Analog Voltage



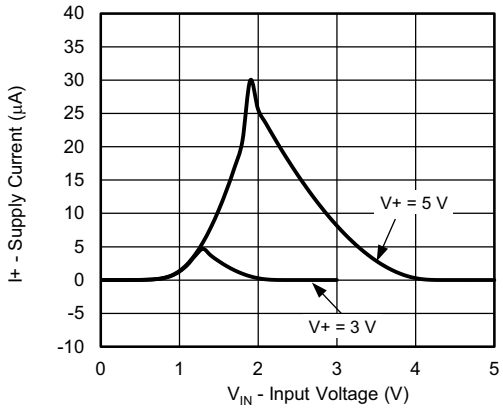
On-Resistance vs. Analog Voltage



Leakage Current vs. Analog Voltage

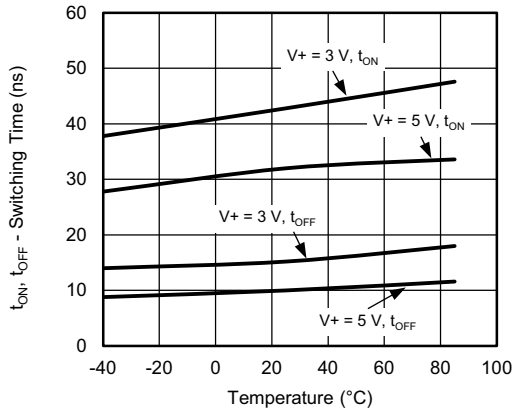


Leakage Current vs. Temperature

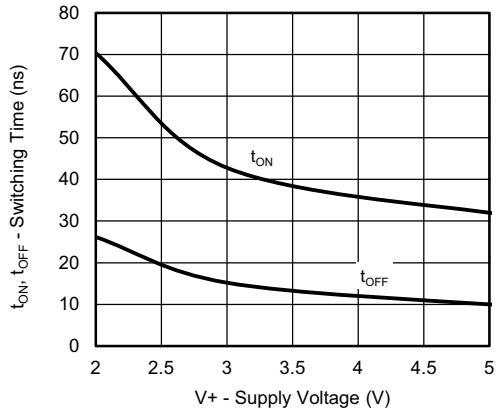


Supply Current vs. Input Voltage

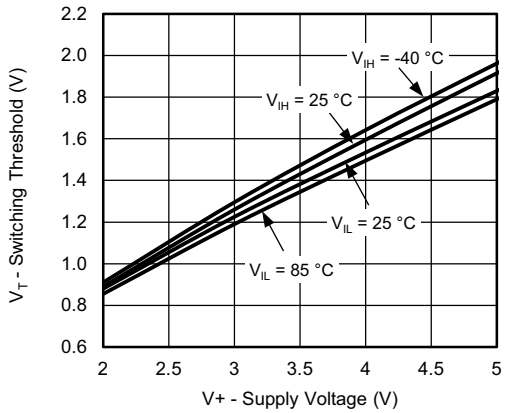
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



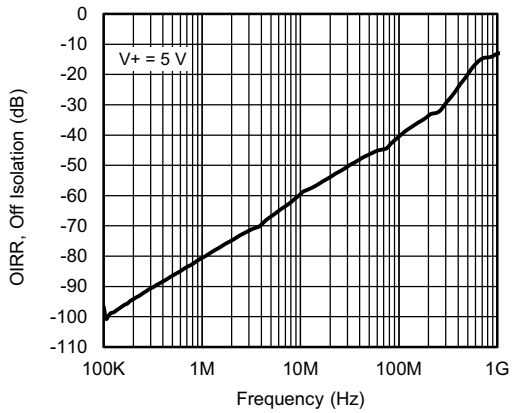
Switching Time vs. Temperature



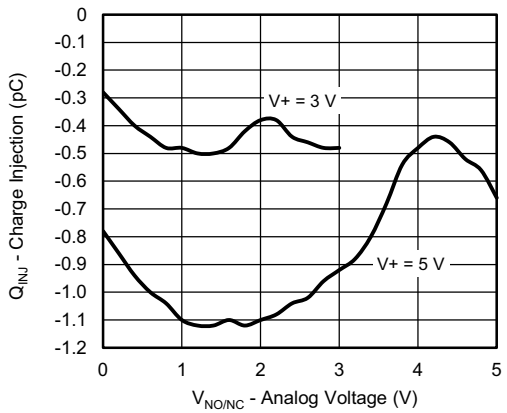
Switching Time vs. Supply Voltage



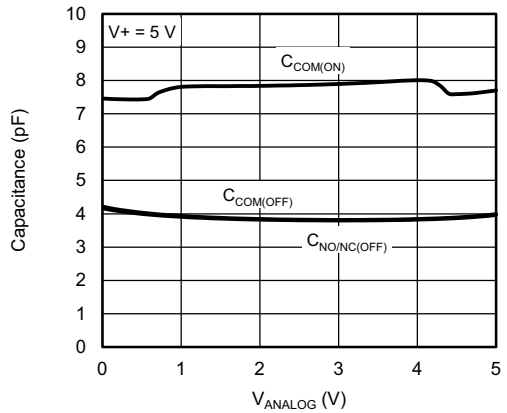
Switching Threshold vs. Supply Voltage



OIRR, Off Isolation vs. Frequency

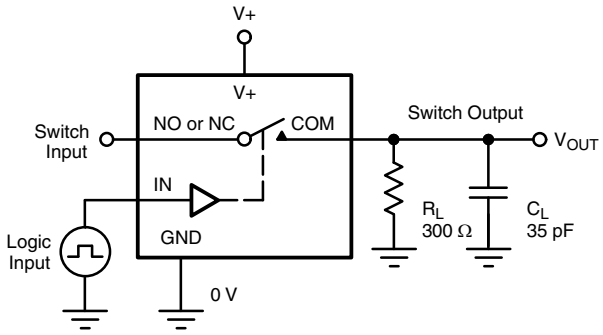


Charge Injection vs. Analog Voltage



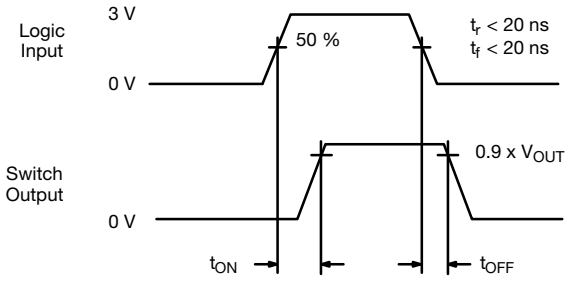
Capacitance

TEST CIRCUITS



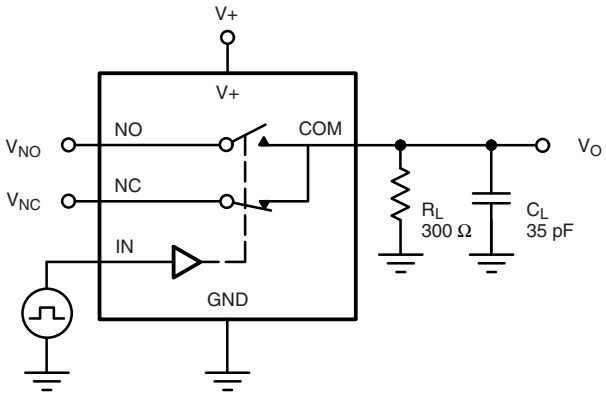
C_L (includes fixture and stray capacitance)

$$V_{OUT} = V_{COM}\left(\frac{R_L}{R_L + R_{ON}}\right)$$



Logic "1" = switch on
Logic input waveforms inverted for switches that have the opposite logic sense.

Figure 1. Switching Time



C_L (includes fixture and stray capacitance)

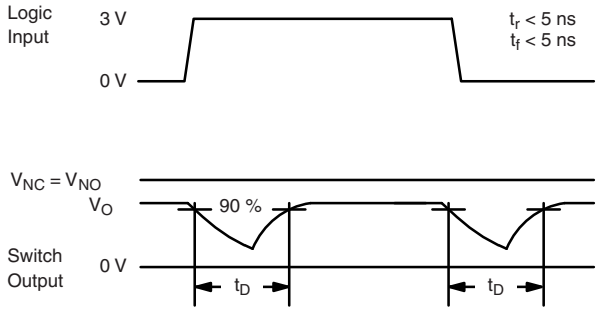
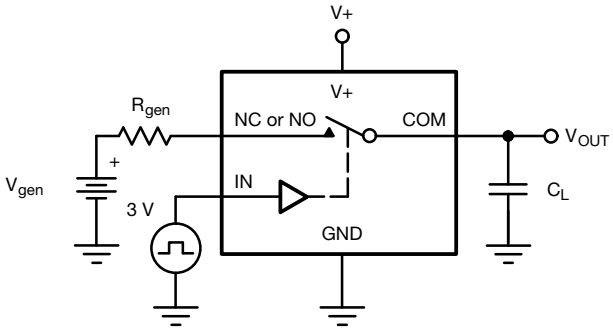
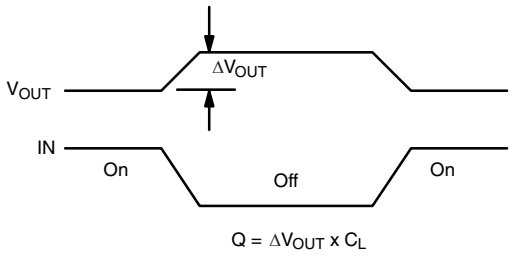


Figure 2. Break-Before-Make Interval





$Q = \Delta V_{OUT} \times C_L$

IN depends on switch configuration: input polarity determined by sense of switch.

Figure 3. Charge Injection

TEST CIRCUITS

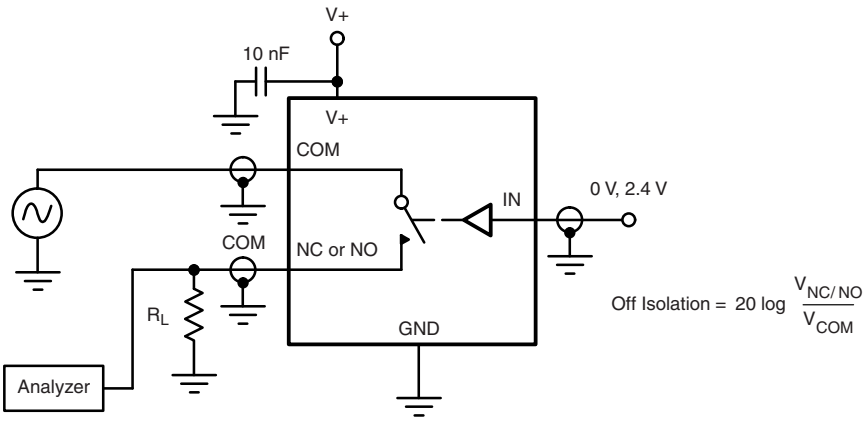


Figure 4. Off-Isolation

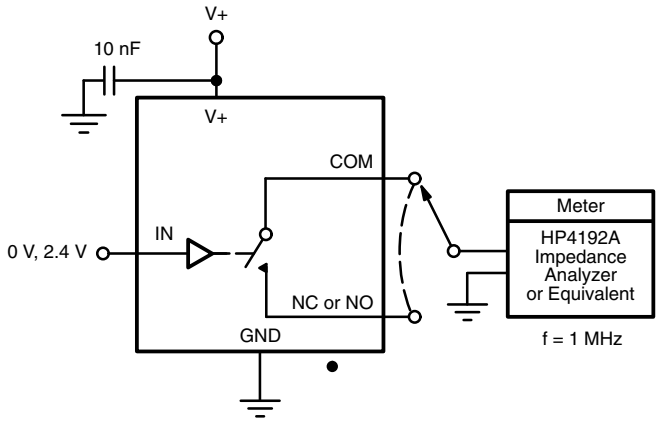
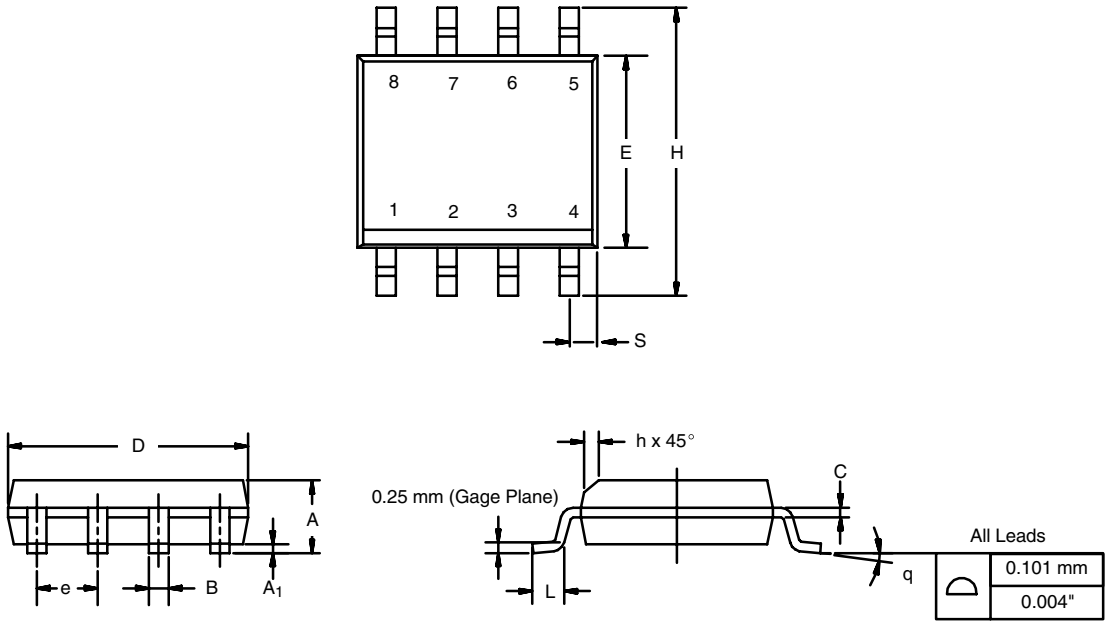


Figure 5. Channel Off/On Capacitance

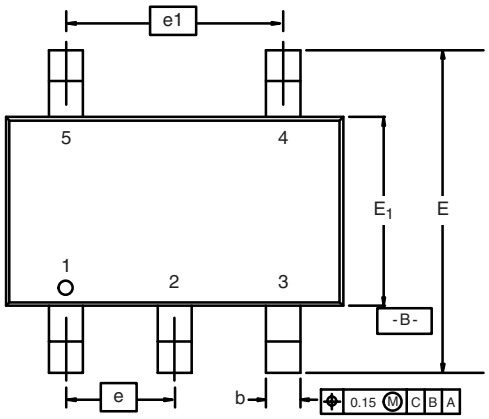
SOIC (NARROW): 8-LEAD
JEDEC Part Number: MS-012



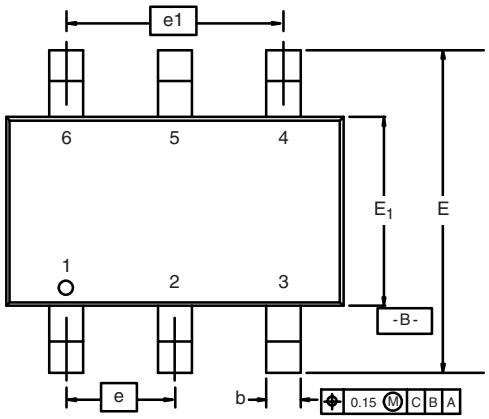
DIM	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A_1	0.10	0.20	0.004	0.008
B	0.35	0.51	0.014	0.020
C	0.19	0.25	0.0075	0.010
D	4.80	5.00	0.189	0.196
E	3.80	4.00	0.150	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
h	0.25	0.50	0.010	0.020
L	0.50	0.93	0.020	0.037
q	0°	8°	0°	8°
S	0.44	0.64	0.018	0.026
ECN: C-06527-Rev. I, 11-Sep-06 DWG: 5498				

TSOP: 5/6–LEAD

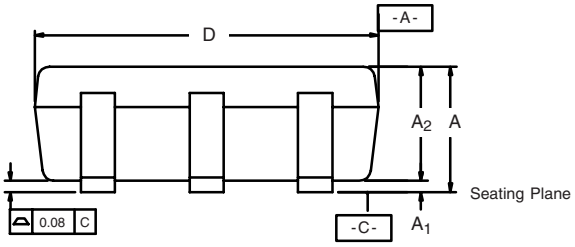
JEDEC Part Number: MO-193C

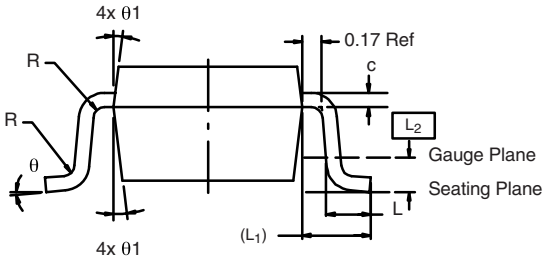


5-LEAD TSOP



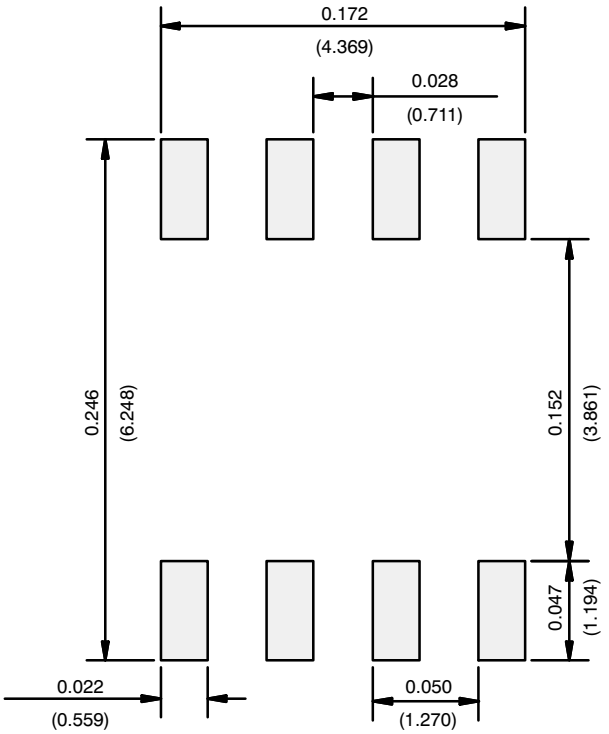
6-LEAD TSOP





Dim	MILLIMETERS			INCHES		
	Min	Nom	Max	Min	Nom	Max
A	0.91	-	1.10	0.036	-	0.043
A_1	0.01	-	0.10	0.0004	-	0.004
A_2	0.90	-	1.00	0.035	0.038	0.039
b	0.30	0.32	0.45	0.012	0.013	0.018
c	0.10	0.15	0.20	0.004	0.006	0.008
D	2.95	3.05	3.10	0.116	0.120	0.122
E	2.70	2.85	2.98	0.106	0.112	0.117
E_1	1.55	1.65	1.70	0.061	0.065	0.067
e	0.95 BSC			0.0374 BSC		
e_1	1.80	1.90	2.00	0.071	0.075	0.079
L	0.32	-	0.50	0.012	-	0.020
L_1	0.60 Ref			0.024 Ref		
L_2	0.25 BSC			0.010 BSC		
R	0.10	-	-	0.004	-	-
θ	0°	4°	8°	0°	4°	8°
$θ_1$	7° Nom			7° Nom		
ECN: C-06593-Rev. I, 18-Dec-06 DWG: 5540						

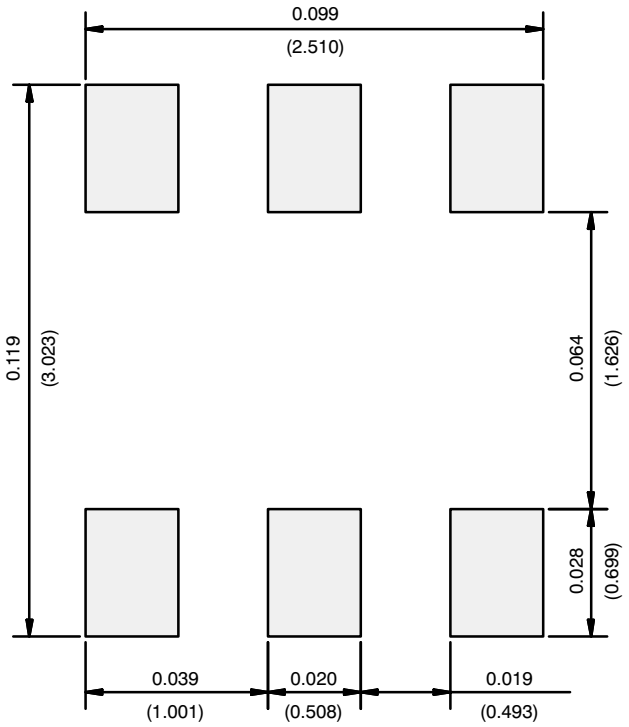
RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads
Dimensions in Inches/(mm)

Return to Index

RECOMMENDED MINIMUM PADS FOR TSOP-6



Recommended Minimum Pads
Dimensions in Inches/(mm)

Return to Index

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, “Vishay”), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay’s knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer’s responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer’s technical experts. Product specifications do not expand or otherwise modify Vishay’s terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.